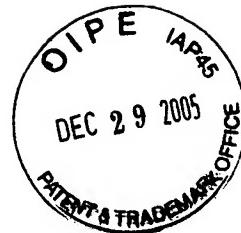


OLIFF & BERRIDGE, PLC

ATTORNEYS AT LAW

Application Data Sheet**Applicant Information**

Applicant Authority type::	Inventor
Primary Citizenship Country::	Japan
Status::	Full Capacity
Given Name::	Masahiro
Family Name::	SAKURADA
City of Residence::	Fukushima
Country of Residence::	JAPAN

Applicant Authority Type::	Inventor
Primary Citizenship Country::	Japan
Status::	Full Capacity
Given Name::	Izumi
Family Name::	FUSEGAWA
City of Residence::	Fukushima
Country of Residence::	JAPAN

Correspondence Information

Correspondence Customer Number:: 25944

Application Information

Application Type::	National Phase
Subject Matter::	Utility
CD-ROM or CD-R::	None
Title::	METHOD OF PRODUCING P-DOPED SILICON SINGLE CRYSTAL AND P- DOPED N-TYPE SILICON SINGLE CRYSTAL WAFER

Attorney Docket Number:: 124231

Suggested Drawing Figure::

Total Drawing Sheets:: 4

Small Entity:: No

Representative Information

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Domestic Priority Information					
Application::	Continuity Type::	Parent Application::	Parent Filing Date::		
This Application is a	National Stage of	PCT/JP03/016794	12/25/03		
Foreign Priority Information					
Country::	Application Number::	Filing Date::	Priority Claimed::		
JAPAN	2003-10436	1/17/03	Yes		
Assignee Information					
Assignee Name::	SHIN-ETSU HANDOTAI CO., LTD.				
Street of mailing address::	4-2, Marunouchi 1-chome,				
City of mailing address::	Chiyoda-ku,				
State or Province of mailing address::	Tokyo,				
Country of mailing address::	JAPAN				